Data Sheet: Technical Data

Document Number: MC9RS08LA8

Rev. 2, 1/2012



## MC9RS08LA8





### MC9RS08LA8

#### Features:

- 8-Bit RS08 Central Processor Unit (CPU)
  - Up to 20 MHz CPU at 2.7 V to 5.5 V across temperature range of –40°C to 85°C
  - Subset of HC08 instruction set with added BGND instruction
- · On-Chip Memory
  - 8 KB flash read/program/erase over full operating voltage and temperature
  - 256-byte random-access memory (RAM)
  - Security circuitry to prevent unauthorized access to flash contents
- Power-Saving Modes
  - Wait and stop
- Clock Source Options
  - Oscillator (XOSC) Loop-control Pierce oscillator; crystal or ceramic resonator range of 31.25 kHz to 39.0625 kHz or 1 MHz to 16 MHz
  - Internal clock source (ICS) Internal clock source module containing a frequency-locked-loop (FLL) controlled by internal or external reference; supports bus frequencies up to 10 MHz
- · System Protection
  - Watchdog computer operating properly (COP) reset with option to run from dedicated 1 kHz internal clock source or bus clock
  - Low-voltage detection with reset or interrupt; selectable trip points
  - Illegal opcode detection with reset
  - Illegal address detection with reset
  - Flash block protection
- Development Support
  - Single-wire background debug interface
  - Breakpoint capability to allow single breakpoint setting during in-circuit debugging
- Peripherals

- LCD Up to 8 × 21 or 4 × 25 segments; compatible with 5 V or 3 V LCD glass displays using on-chip charge pump; functional in wait, stop modes for very low power LCD operation; frontplane and backplane pins multiplexed with GPIO functions; selectable frontplane and backplane configurations
- ADC 6-channel, 10-bit resolution; 2.5 μs conversion time; automatic compare function; 1.7 mV/°C temperature sensor; internal bandgap reference channel; operation in stop; fully functional from 2.7 V to 5.5 V.
- TPM One 2-channel 16-bit timer/pulse-width modulator (TPM) module
- SCI One 2-channel serial communications interface module with optional 13-bit break; LIN extensions
- SPI One serial peripheral interface module in 8-bit data length mode with a receive data buffer hardware match function
- ACMP Analog comparator with option to compare to internal reference
- MTIM One 8-bit modulo timer
- **KBI** 8-pin keyboard interrupt module
- RTI One real-time interrupt module with optional reference clock.
- Input/Output
  - 33 GPIOs including 1 output only pin and 1 input only pin.
  - Hysteresis and configurable pullup device on all input pins; configurable slew rate and drive strength on all output pins.
- · Package Options
  - 48-pin QFN
  - 48-pin LQFP

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# **Table of Contents**

| MCL   | J Block Diagram   |   | 3.8.1 Control Timing   | 17              |
|-------|---|---|--|-----------------|
| Pin A | Assignments4  |   | 3.8.2 TPM/MTIM Module Timing   | 18              |
| Elec  | trical Characteristics7   |   | 3.9 Analog Comparator (ACMP) Electrical  | 19              |
| 3.1   | Parameter Classification  |   | 3.10 Internal Clock Source Characteristics   | 19              |
| 3.2   | Absolute Maximum Ratings  |   | 3.11 ADC Characteristics   | 20              |
| 3.3   | Thermal Characteristics   |   | 3.12 AC Characteristics  | 22              |
| 3.4   | ESD Protection and Latch-Up Immunity                            |   | 3.12.1 Control Timing  | 22              |
| 3.5   | DC Characteristics  |   | 3.13 Flash Specifications  | 23              |
| 3.6   | Supply Current Characteristics                                  | 4   | Ordering Information   | 25              |
| 3.7   | External (XOSC) and Internal (ICS) Oscillator                   | 5   | Package Information and Mechanical Drawings  | 26              |
|       | Characteristics   |   |  |                 |
| 3.8   | AC Characteristics  |   |  |                 |
|       | Pin A<br>Elect<br>3.1<br>3.2<br>3.3<br>3.4<br>3.5<br>3.6<br>3.7 | Pin Assignments         4           Electrical Characteristics         7           3.1 Parameter Classification         7           3.2 Absolute Maximum Ratings         7           3.3 Thermal Characteristics         8           3.4 ESD Protection and Latch-Up Immunity         9           3.5 DC Characteristics         10           3.6 Supply Current Characteristics         14           3.7 External (XOSC) and Internal (ICS) Oscillator | 3.1       Parameter Classification       .7         3.2       Absolute Maximum Ratings       .7         3.3       Thermal Characteristics       .8         3.4       ESD Protection and Latch-Up Immunity       .9         3.5       DC Characteristics       .10         3.6       Supply Current Characteristics       .14       4         3.7       External (XOSC) and Internal (ICS) Oscillator 5       .15 | Pin Assignments |

# **Revision History**

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The following revision history table summarizes changes contained in this document.

| Revision | Date      | Description of Changes  |
|----------|-----------|---|
| 1        | 10/9/2008 | Initial public released.  |
| 2        | 1/30/2012 | Updated the case number of 48-pin QFN to 1975; updated 48-pin QFN case outline drawing. |

## **Related Documentation**

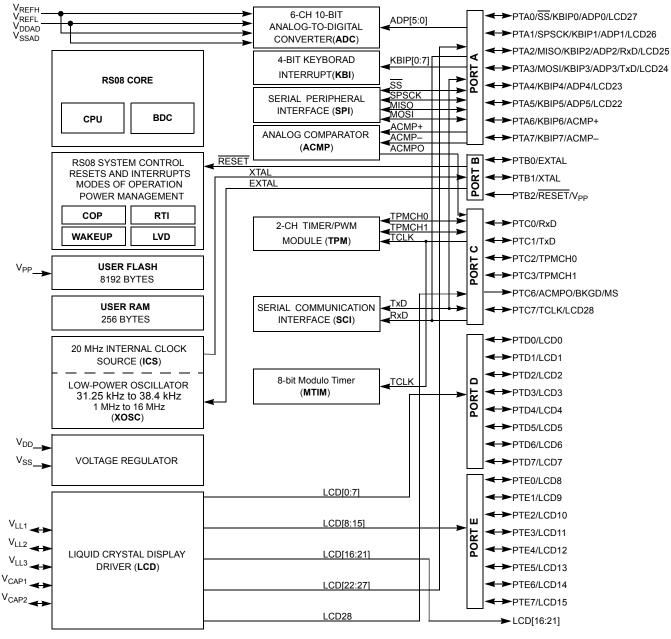
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#### Reference Manual (MC9RS08LA8RM)

Contains extensive product information including modes of operation, memory, resets and interrupts, register definition, port pins, CPU, and all module information.

# 1 MCU Block Diagram

The block diagram, Figure 1, shows the structure of the MC9RS08LA8 MCU.



- NOTES:
  - 1. PTB2/RESET/V<sub>PP</sub> is an input only pin when used as port pin
  - 2. PTC6/ACMPO/BKGD/MS is an output only pin

Figure 1. MC9RS08LA8 Series Block Diagram

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

# 2 Pin Assignments

This section shows the pin assignments in the packages available for the MC9RS08LA8 series.

Table 1. Pin Availability by Package Pin-Count

| Pin Number | < Lowest <b>Priority</b> > Highest |       |        |                                      |       |                   |  |  |  |
|------------|------------------------------------|-------|--------|--------------------------------------|-------|-------------------|--|--|--|
| 48         | Port Pin                           | Alt 1 | Alt 2  | Alt 3                                | Alt 4 | Alt 5             |  |  |  |
| 1          | PTD7                               |       |        |                                      | LCD7  |                   |  |  |  |
| 2          | PTD6                               |       |        |                                      |       | LCD6              |  |  |  |
| 3          | PTD5                               |       |        |                                      |       | LCD5              |  |  |  |
| 4          | PTD4                               |       |        |                                      |       | LCD4              |  |  |  |
| 5          | PTD3                               |       |        |                                      |       | LCD3              |  |  |  |
| 6          | PTD2                               |       |        |                                      |       | LCD2              |  |  |  |
| 7          | PTD1                               |       |        |                                      |       | LCD1              |  |  |  |
| 8          | PTD0                               |       |        |                                      |       | LCD0              |  |  |  |
| 9          |                                    |       |        |                                      |       | V <sub>CAP1</sub> |  |  |  |
| 10         |                                    |       |        |                                      |       | V <sub>CAP2</sub> |  |  |  |
| 11         |                                    |       |        |                                      |       | V <sub>LL1</sub>  |  |  |  |
| 12         |                                    |       |        |                                      |       | V <sub>LL2</sub>  |  |  |  |
| 13         |                                    |       |        |                                      |       | $V_{LL3}$         |  |  |  |
| 14         | PTA6                               | KBIP6 | ACMP+  |                                      |       |                   |  |  |  |
| 15         | PTA7                               | KBIP7 | ACMP-  |                                      |       |                   |  |  |  |
| 16         |                                    |       |        | V <sub>SSAD</sub> /V <sub>REFL</sub> |       |                   |  |  |  |
| 17         |                                    |       |        | V <sub>DDAD</sub> /V <sub>REFH</sub> |       |                   |  |  |  |
| 18         | PTB0                               |       |        | EXTAL                                |       |                   |  |  |  |
| 19         | PTB1                               |       |        | XTAL                                 |       |                   |  |  |  |
| 20         |                                    |       |        | $V_{DD}$                             |       |                   |  |  |  |
| 21         |                                    |       |        | V <sub>SS</sub>                      |       |                   |  |  |  |
| 22         | PTB2                               |       | RESET  | V <sub>PP</sub>                      |       |                   |  |  |  |
| 23         | PTC0                               |       | RxD    |                                      |       |                   |  |  |  |
| 24         | PTC1                               |       | TxD    |                                      |       |                   |  |  |  |
| 25         | PTC2                               |       | TPMCH0 |                                      |       |                   |  |  |  |
| 26         | PTC3                               |       | TPMCH1 |                                      |       |                   |  |  |  |
| 27         | PTC6                               | ACMPO | BKGD   | MS                                   |       |                   |  |  |  |
| 28         | PTC7                               |       | TCLK   |                                      |       | LCD28             |  |  |  |
| 29         | PTA0                               | SS    | KBIP0  | ADP0                                 |       | LCD27             |  |  |  |
| 30         | PTA1                               | SPSCK | KBIP1  | ADP1                                 |       | LCD26             |  |  |  |
| 31         | PTA2                               | MISO  | KBIP2  | RxD                                  | ADP2  | LCD25             |  |  |  |

Table 1. Pin Availability by Package Pin-Count (continued)

| Pin Number | < Lowest Priority> Highest |       |       |       |       |       |  |  |  |
|------------|----------------------------|-------|-------|-------|-------|-------|--|--|--|
| 48         | Port Pin                   | Alt 1 | Alt 2 | Alt 3 | Alt 4 | Alt 5 |  |  |  |
| 32         | PTA3                       | MOSI  | KBIP3 | TxD   | ADP3  | LCD24 |  |  |  |
| 33         | PTA4                       |       | KBIP4 | ADP4  |       | LCD23 |  |  |  |
| 34         | PTA5                       |       | KBIP5 | ADP5  |       | LCD22 |  |  |  |
| 35         |                            |       |       |       |       | LCD21 |  |  |  |
| 36         |                            |       |       |       |       | LCD20 |  |  |  |
| 37         |                            |       |       |       |       | LCD19 |  |  |  |
| 38         |                            |       |       |       |       | LCD18 |  |  |  |
| 39         |                            |       |       |       |       | LCD17 |  |  |  |
| 40         |                            |       |       |       |       | LCD16 |  |  |  |
| 41         | PTE7                       |       |       |       |       | LCD15 |  |  |  |
| 42         | PTE6                       |       |       |       |       | LCD14 |  |  |  |
| 43         | PTE5                       |       |       |       |       | LCD13 |  |  |  |
| 44         | PTE4                       |       |       |       |       | LCD12 |  |  |  |
| 45         | PTE3                       |       |       |       |       | LCD11 |  |  |  |
| 46         | PTE2                       |       |       |       |       | LCD10 |  |  |  |
| 47         | PTE1                       |       |       |       |       | LCD9  |  |  |  |
| 48         | PTE0                       |       |       |       |       | LCD8  |  |  |  |

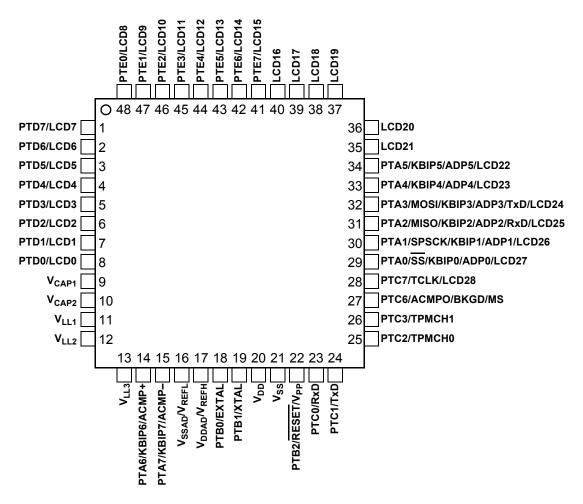


Figure 2. MC9RS08LA8 Series in 48-Pin QFN/LQFP Package

This chapter contains electrical and timing specifications.

### 3.1 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

**Table 2. Parameter Classifications** 

| Р | Those parameters are guaranteed during production testing on each individual device.   |
|---|--|
| С | Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.  |
| Т | Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category. |
| D | Those parameters are derived mainly from simulations.  |

### NOTE

The classification is shown in the column labeled "C" in the parameter tables where appropriate.

## 3.2 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in Table 3 may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this chapter.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either  $V_{SS}$  or  $V_{DD}$ ) or the programmable pull-up resistor associated with the pin is enabled.

**Table 3. Absolute Maximum Ratings** 

| Rating   | Symbol           | Value                         | Unit |
|--|------------------|-------------------------------|------|
| Supply voltage   | $V_{DD}$         | 2.7 to 5.5                    | V    |
| Maximum current into V <sub>DD</sub>   | I <sub>DD</sub>  | 120                           | mA   |
| Digital input voltage  | V <sub>In</sub>  | –0.3 to V <sub>DD</sub> + 0.3 | V    |
| Instantaneous maximum current Single pin limit (applies to all port pins) <sup>1, 2, 3</sup> | I <sub>D</sub>   | ±25                           | mA   |
| Storage temperature range  | T <sub>stg</sub> | -55 to 150                    | °C   |

- Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V<sub>DD</sub>) and negative (V<sub>SS</sub>) clamp voltages, then use the larger of the two resistance values.
- <sup>2</sup> All functional non-supply pins are internally clamped to V<sub>SS</sub> and V<sub>DD</sub> except the RESET/V<sub>PP</sub> pin which is internally clamped to V<sub>SS</sub> only.
- Power supply must maintain regulation within operating V<sub>DD</sub> range during instantaneous and operating maximum current conditions. If positive injection current (V<sub>In</sub> > V<sub>DD</sub>) is greater than I<sub>DD</sub>, the injection current may flow out of V<sub>DD</sub> and could result in external power supply going out of regulation. Ensure external V<sub>DD</sub> load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low which would reduce overall power consumption.

### 3.3 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits and it is user-determined rather than being controlled by the MCU design. In order to take  $P_{I/O}$  into account in power calculations, determine the difference between actual pin voltage and  $V_{SS}$  or  $V_{DD}$  and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and  $V_{SS}$  or  $V_{DD}$  will be very small.

**Symbol** Value Unit Rating  $T_L$  to  $T_H$ Operating temperature range (packaged)  $T_A$ °C -40 to 85 °C Maximum junction temperature 105  $T_{\text{JMAX}}$ Thermal resistance Single layer board 48-pin LQFP 71 48-pin QFN 84 °C/W Four layer board 48-pin LQFP 49 48-pin QFN

**Table 4. Thermal Characteristics** 

The average chip-junction temperature (TJ) in °C can be obtained from:

$$T_{,l} = T_{\Delta} + (P_{D} \times \theta_{,l\Delta})$$
 Eqn. 1

where:

 $T_A = Ambient temperature, °C$ 

 $\theta_{JA}$  = Package thermal resistance, junction-to-ambient, °C /W

 $P_{D} = P_{int} + P_{I/O}$ 

 $P_{int} = I_{DD} \times V_{DD}$ , Watts chip internal power

 $P_{I/O}$  = Power dissipation on input and output pins user determined

For most applications,  $P_{I/O} \ll P_{int}$  and can be neglected. An approximate relationship between PD and TJ

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

(if PI/O is neglected) is:

$$P_D = K \div (T_J + 273^{\circ}C)$$
 Eqn. 2

Solving Equation 1 and Equation 2 for K gives:

$$K = P_D \times (T_A + 273^{\circ}C) + \theta_{JA} \times (PD)^2$$
 Eqn. 3

where K is a constant pertaining to the particular part. K can be determined from Equation A-3 by measuring  $P_D$  (at equilibrium) for a known  $T_A$ . Using this value of K, the values of  $P_D$  and  $P_D$  and  $P_D$  are obtained by solving equations 1 and 2 iteratively for any value of  $P_D$ .

## 3.4 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions must be used to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

All ESD testing is in conformity with AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits. During the device qualification ESD stresses were performed for the human body model (HBM), the machine model (MM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

| Model         | Description                 | Symbol | Value | Unit |
|---------------|-----------------------------|--------|-------|------|
|               | Series resistance           | R1     | 1500  | Ω    |
| Human<br>Body | Storage capacitance         | С      | 100   | pF   |
| ,             | Number of pulses per pin    | _      | 3     | _    |
|               | Series resistance           | R1     | 0     | Ω    |
| Machine       | Storage capacitance         | С      | 200   | pF   |
|               | Number of pulses per pin    | _      | 3     | _    |
| Latch-up      | Minimum input voltage limit | _      | -2.5  | V    |
| Lateri-up     | Maximum input voltage limit | _      | 7.5   | V    |

Table 5. ESD and Latch-up Test Conditions

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

| No. | Rating <sup>1</sup>                       | Symbol           | Min               | Max | Unit |
|-----|---|------------------|-------------------|-----|------|
| 1   | Human body model (HBM)                    | $V_{HBM}$        | ±2000             | _   | V    |
| 2   | Machine model (MM)                        | V <sub>MM</sub>  | ±200              | _   | V    |
| 3   | Charge device model (CDM)                 | V <sub>CDM</sub> | ±500              | _   | V    |
| 4   | Latch-up current at T <sub>A</sub> = 85°C | I <sub>LAT</sub> | ±100 <sup>2</sup> | _   | mA   |
| 4   | Latch-up current at T <sub>A</sub> = 85°C | I <sub>LAT</sub> | ±75 <sup>3</sup>  | _   | mA   |

Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

### 3.5 DC Characteristics

This section includes information about power supply requirements, I/O pin characteristics, and power supply current in various operating modes.

Table 7. DC Characteristics (Temperature Range = -40 to 85°C Ambient)

| Num | С | Parameter  | Symbol           | Min                   | Typical | Max                  | Unit |
|-----|---|--|------------------|-----------------------|---------|----------------------|------|
| 1   | Р | Supply voltage (run, wait and stop modes)<br>0 < f <sub>Bus</sub> <10 MHz  | $V_{DD}$         | 2.7                   |         | 5.5                  | V    |
| 2   | D | Minimum RAM retention supply voltage applied to $V_{DD}$   | $V_{RAM}$        | 0.8 <sup>1</sup>      |         | _                    | V    |
| 3   | Р | Low-voltage Detection threshold $(V_{DD}$ falling)   | V <sub>LVD</sub> |                       | 1.8     |                      | V    |
| 4   | С | Power on RESET (POR) voltage   | $V_{POR}$        | 0.9                   | 1.4     | 1.7                  | V    |
| 5   | Р | Input high voltage (V <sub>DD</sub> > 5V) (all digital inputs)   | V <sub>IH</sub>  | $0.70 \times V_{DD}$  | _       | _                    | V    |
| 6   | Р | Input high voltage (2.7 V $\leq$ V <sub>DD</sub> $\leq$ 5 V) (all digital inputs)  | V <sub>IH</sub>  | $0.85 \times V_{DD}$  | _       | _                    | V    |
| 7   | Р | Input low voltage (V <sub>DD</sub> > 5 V) (all digital inputs)   | V <sub>IL</sub>  | _                     | _       | $0.30 \times V_{DD}$ | V    |
| 8   | Р | Input low voltage (2.7 V $\leq$ V <sub>DD</sub> $\leq$ 5 V) (all digital inputs)   | V <sub>IL</sub>  | _                     | _       | $0.30 \times V_{DD}$ | ٧    |
| 9   | С | Input hysteresis (all digital inputs)  | V <sub>hys</sub> | $0.06 \times V_{DD}$  | _       | _                    | V    |
| 10  | Р | Input leakage current (per pin) V <sub>In</sub> = V <sub>DD</sub> or V <sub>SS</sub> , all input only pins   | lin              | _                     | 0.025   | 1.0                  | μА   |
| 11  | Р | High impedance (off-state) leakage current (per pin) $V_{In} = V_{DD}$ or $V_{SS}$ , all input/output  | loz              | _                     | 0.025   | 1.0                  | μА   |
| 12  | С | Internal pullup/pulldown resistors <sup>2</sup> (all port pins)  | R <sub>PU</sub>  | 20                    | 45      | 65                   | kΩ   |
| 13  | Р | Output high voltage (all ports) <sup>3,4</sup> $I_{OH} = -5 \text{ mA } (V_{DD} \ge 4.5 \text{ V})$ $I_{OH} = -3 \text{ mA } (V_{DD} \ge 3 \text{ V})$ | V <sub>OH</sub>  | V <sub>DD</sub> – 0.8 | _       | _                    | V    |
| 14  | C | Maximum total I <sub>OH</sub> for all port pins  | [Іонт]           | _                     | _       | 100                  | mA   |

<sup>&</sup>lt;sup>2</sup> These pins meet JESD78A Class II (section 1.2) Level A (section 1.3) requirement of  $\pm 100$  mA.

<sup>&</sup>lt;sup>3</sup> This pin meets JESD78A Class II (section 1.2) Level B (section 1.3) characterization to  $\pm 75$  mA.

| Num | С | Parameter   | Symbol           | Min | Typical | Max        | Unit     |
|-----|---|---|------------------|-----|---------|------------|----------|
| 15  | Р | Output low voltage (port A) <sup>4</sup> $I_{OL} = 5 \text{ mA } (V_{DD} \ge 4.5 \text{ V})$ $I_{OL} = 3 \text{ mA } (V_{DD} \ge 3 \text{ V})$                                  | V <sub>OL</sub>  |     |         | 0.8<br>0.8 | V        |
| 16  | С | Maximum total IoL for all port pins   | I <sub>OLT</sub> | _   | _       | 100        | mA       |
| 17  | С | dc injection current <sup>5,6,7</sup> V <sub>In</sub> < V <sub>SS,</sub> V <sub>In</sub> > V <sub>DD</sub> Single pin limit  Total MCU limit, includes sum of all stressed pins |                  | _   |         | 0.2<br>0.8 | mA<br>mA |
| 18  | С | Input capacitance (all non-supply pins)   | C <sub>In</sub>  | _   |         | 7          | pF       |

<sup>&</sup>lt;sup>1</sup> This parameter is characterized and not tested on each device.

<sup>&</sup>lt;sup>7</sup> This parameter is characterized and not tested on each device.

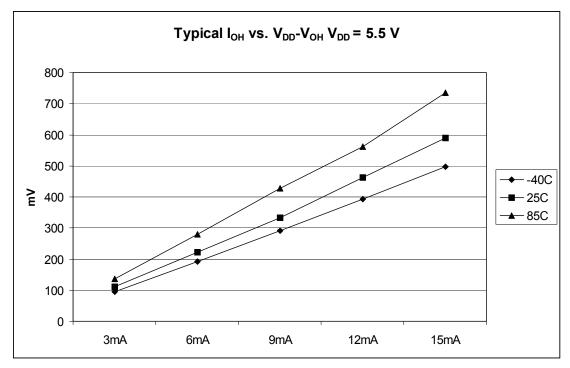


Figure 3. Typical  $I_{OH}$  vs.  $V_{DD}$ - $V_{OH}$  ( $V_{DD}$  = 5.5 V)

<sup>&</sup>lt;sup>2</sup> Measurement condition for pull resistors:  $V_{ln} = V_{SS}$  for pullup and  $V_{ln} = V_{DD}$  for pulldown.

 $<sup>^{3}</sup>$  The  $I_{OH}$  is for high output drive strength.

<sup>&</sup>lt;sup>4</sup> It is tested under high output drive strength only.

<sup>&</sup>lt;sup>5</sup> All functional non-supply pins are internally clamped to  $V_{SS}$  and  $V_{DD}$  except the RESET/ $V_{PP}$  which is internally clamped to  $V_{SS}$  only

<sup>&</sup>lt;sup>6</sup> Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

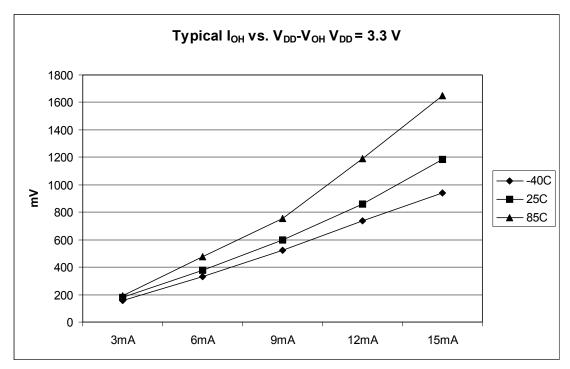


Figure 4. Typical  $I_{OH}$  vs.  $V_{DD}$ - $V_{OH}$  ( $V_{DD}$  = 3.3 V)

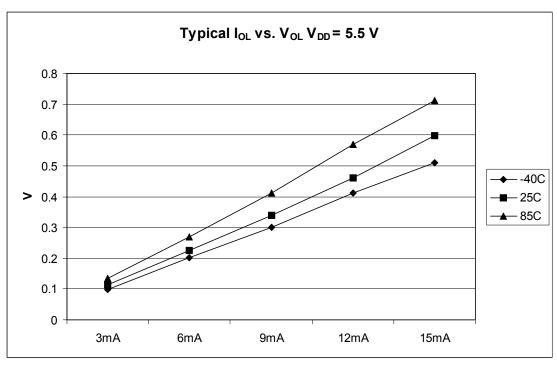


Figure 5. Typical  $I_{OL}$  vs.  $V_{OL}$  ( $V_{DD}$  = 5.5 V)

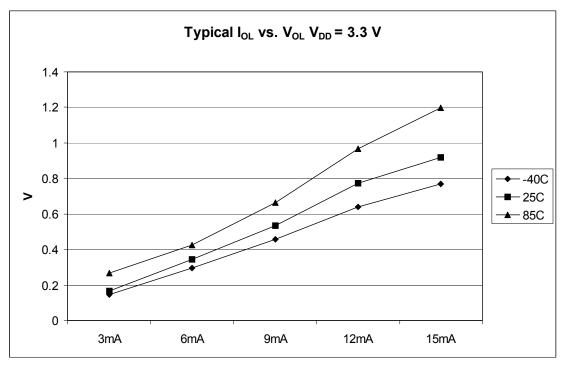


Figure 6. Typical  $I_{OL}$  vs.  $V_{OL}$  ( $V_{DD}$  = 3.3 V)

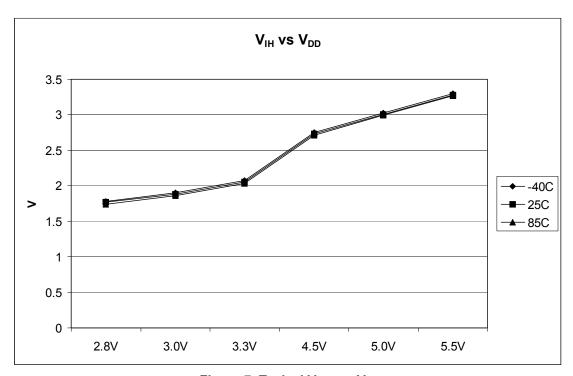


Figure 7. Typical  $V_{DD}$  vs.  $V_{IH}$ 

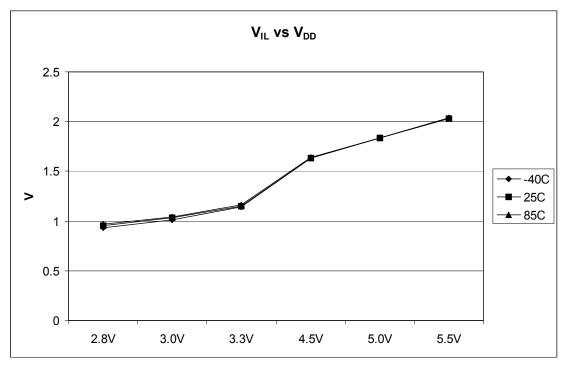


Figure 8. Typical  $V_{\rm DD}$  vs.  $V_{\rm IL}$ 

# 3.6 Supply Current Characteristics

**Table 8. Supply Current Characteristics** 

| Num | С | Parameter                                   | Symbol             | V <sub>DD</sub> (V) | Typical <sup>1</sup> | Unit |
|-----|---|---|--------------------|---------------------|----------------------|------|
|     |   |   |                    | 5                   | 3.71                 | mA   |
|     | _ | Run supply current <sup>2</sup> measured at | DI                 | 3.3                 | 3.68                 | mA   |
| 1   | Р | (f <sub>Bus</sub> = 10 MHz)                 | RI <sub>DD10</sub> | 3                   | 3.67                 | mA   |
|     |   |   |                    | 2.7                 | 3.66                 | mA   |
|     |   |   |                    | 5                   | 1.37                 | mA   |
|     | _ | Wait mode supply current                    | \\/\/I             | 3.3                 | 1.37                 | mA   |
| 2   | Р | wait mode supply current                    | WI <sub>DD1</sub>  | 3                   | 1.37                 | mA   |
|     |   |   |                    | 2.7                 | 1.36                 | mA   |
|     |   |   |                    | 5                   | 1.40                 | μΑ   |
|     | _ | Stop mode supply current                    | Q1                 | 3.3                 | 1.35                 | μА   |
| 3   | Р | Stop mode supply current                    | SI <sub>DD</sub>   | 3                   | 1.31                 | μА   |
|     |   |   |                    | 2.7                 | 1.25                 | μΑ   |
|     |   |   |                    | 5                   | 125.45               | μА   |
|     |   | ADC adder from stop <sup>3</sup>            |                    | 3.3                 | 122.04               | μА   |
| 4   | С | ADC adder from stop                         | _                  | 3                   | 121.59               | μА   |
|     |   |   |                    | 2.7                 | 121.22               | μΑ   |
| _   |   | ACMP adder from stop                        |                    | 5                   | 21                   | μΑ   |
| 5   | С | (ACME = 1)                                  |                    | 3                   | 18.5                 | μА   |

15

**Table 8. Supply Current Characteristics (continued)** 

| Num | С | Parameter                                    | Symbol | V <sub>DD</sub> (V) | Typical <sup>1</sup> | Unit |
|-----|---|--|--------|---------------------|----------------------|------|
| 6   | _ | RTI adder from stop                          | _      | 5                   | 2.4                  | μΑ   |
| 0   | C | with 1 kHz clock source enabled <sup>4</sup> |        | 3                   | 1.9                  | μΑ   |
| 0   |   | LVI adder from stop                          |        | 5                   | 70                   | μΑ   |
| 8   |   | (LVDE = 1 and LVDSE = 1)                     | _      | 3                   | 65                   | μΑ   |

<sup>&</sup>lt;sup>1</sup> Typicals are measured at 25 °C.

## 3.7 External (XOSC) and Internal (ICS) Oscillator Characteristics

Reference Figure 9 for crystal or resonator circuit.

<sup>&</sup>lt;sup>2</sup> Does not include any dc loads on port pins

<sup>&</sup>lt;sup>3</sup> Required asynchronous ADC clock and LVD to be enabled.

Most customers are expected to find that auto-wakeup from stop can be used instead of the higher current wait mode. Wait mode typical is 1.37 mA at 5 V and 3 V with f<sub>Bus</sub> = 10 MHz.

Table 9. External Oscillator Specifications (Temperature Range = -40 to 85°C Ambient)

| Characteristic   | Symbol  | Min              | Typical <sup>1</sup>           | Max              | Unit              |
|--|---|------------------|--------------------------------|------------------|-------------------|
| Oscillator crystal or resonator (EREFS = 1)  Low range, (IREFS = x)  High range, FLL bypassed external (CLKS = 10, IREFS = x)  High range, FLL engaged external (CLKS = 00, IREFS = 0) | f <sub>lo</sub><br>f <sub>hi_byp</sub><br>f <sub>hi_eng</sub> | 32<br>1<br>1     | _<br>_<br>_                    | 38.4<br>10<br>10 | kHz<br>MHz<br>MHz |
| Load capacitors  | C <sub>1</sub><br>C <sub>2</sub>                              |                  | See No                         | ote <sup>2</sup> |                   |
| Feedback resistor Low range (32 kHz to 100 kHz) High range (1 MHz to 16 MHz)   | R <sub>F</sub>  |                  | 10<br>1                        |                  | MΩ<br>MΩ          |
| Series resistor  Low range  Low Gain (HGO = 0)  High Gain (HGO = 1)  High range  Low Gain (HGO = 0)  High Gain (HGO = 1)  ≥ 8 MHz  4 MHz  1 MHz  | R <sub>S</sub>  | _<br>_<br>_<br>_ | 0<br>100<br>0<br>0<br>10<br>20 | _<br>_<br>_<br>_ | kΩ                |
| Crystal start-up time <sup>3, 4</sup> Low range High range   | t<br>CSTL<br>t<br>CSTH  |                  | 500<br>4                       | _                | ms                |
| Square wave input clock frequency (EREFS = 0) FLL bypass external (CLKS = 10) FLL engaged external (CLKS = 00)   | f <sub>extal</sub>  | 0<br>0.03125     |                                | 20<br>5          | MHz               |
| Average internal reference frequency - untrimmed   | f <sub>int_ut</sub>   | 25               | 31.25                          | 41.66            | kHz               |
| Average internal reference frequency - trimmed   | f <sub>int_t</sub>  | 31.25            | 31.25                          | 39.0625          | kHz               |
| DCO output frequency range - untrimmed   | f <sub>dco_ut</sub>   | 12.8             | 16                             | 21.33            | MHz               |
| DCO output frequency range - trimmed   | f <sub>dco_t</sub>  | 16               | 16                             | 20               | MHz               |
| Resolution of trimmed DCO output frequency at fixed voltage and temperature  | $\Delta f_{dco\_res\_t}$                                      | _                | _                              | ±0.2             | %f <sub>dco</sub> |
| Total deviation of trimmed DCO output frequency over voltage and temperature   | $\Delta f_{dco\_t}$   | _                | _                              | ±2               | %f <sub>dco</sub> |
| FLL acquisition time <sup>3,5</sup>  | t <sub>acquire</sub>  | _                | _                              | 1                | ms                |
| Long term Jitter <sup>6</sup> of DCO output clock (averaged over 2ms interval)   | C <sub>Jitter</sub>   | _                | _                              | 0.6              | %f <sub>dco</sub> |

<sup>&</sup>lt;sup>1</sup> Data in Typical column was characterized at 3.0 V, 25 °C or is typical recommended value.

 $<sup>^{2}\,</sup>$  See crystal or resonator manufacturer's recommendation.

 $<sup>^{\</sup>rm 3}$   $\,$  This parameter is characterized and not tested on each device.

<sup>&</sup>lt;sup>4</sup> Proper PC board layout procedures must be followed to achieve specifications.

<sup>&</sup>lt;sup>5</sup> This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f<sub>BUS</sub>. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V<sub>DD</sub> and V<sub>SS</sub> and variation in crystal oscillator frequency increase the C<sub>Jitter</sub> percentage for a given interval.

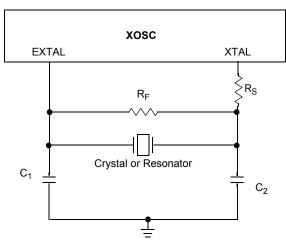


Figure 9. Typical Crystal or Resonator Circuit

### 3.8 AC Characteristics

This section describes ac timing characteristics for each peripheral system.

### 3.8.1 Control Timing

**Table 10. Control Timing** 

| Parameter  | Symbol                                | Min                  | Typical  | Max  | Unit |
|--|---------------------------------------|----------------------|----------|------|------|
| Bus frequency (t <sub>cyc</sub> = 1/f <sub>Bus</sub> )   | f <sub>Bus</sub>                      | 0                    | _        | 10   | MHz  |
| Real time interrupt internal oscillator period   | t <sub>RTI</sub>                      | 700                  | 1000     | 1300 | μS   |
| External RESET pulse width <sup>1</sup>  | t <sub>extrst</sub>                   | 150                  | _        | _    | ns   |
| KBI pulse width <sup>2</sup>   | t <sub>KBIPW</sub>                    | 1.5 t <sub>cyc</sub> | _        | _    | ns   |
| KBI pulse width in stop <sup>1</sup>   | t <sub>KBIPWS</sub>                   | 100                  | _        | _    | ns   |
| Port rise and fall time (load = 50 pF) <sup>3</sup> Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1) | t <sub>Rise</sub> , t <sub>Fall</sub> | _                    | 11<br>35 | _    | ns   |

<sup>1</sup> This is the shortest pulse that is guaranteed to pass through the pin input filter circuitry. Shorter pulses may or may not be recognized.

<sup>&</sup>lt;sup>2</sup> This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

<sup>&</sup>lt;sup>3</sup> Timing is shown with respect to 20% V<sub>DD</sub> and 80% V<sub>DD</sub> levels. Temperature range –40°C to 85°C.

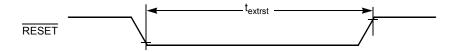


Figure 10. Reset Timing

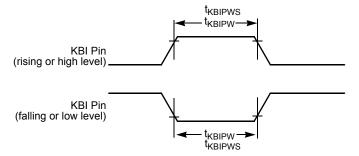


Figure 11. KBI Pulse Width

## 3.8.2 TPM/MTIM Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 11. TPM/MTIM Input Timing

| Function                  | Symbol            | Min | Max                  | Unit             |
|---------------------------|-------------------|-----|----------------------|------------------|
| External clock frequency  | f <sub>TCLK</sub> | 0   | f <sub>Bus</sub> 1/4 | MHz              |
| External clock period     | t <sub>TCLK</sub> | 4   | _                    | t <sub>CYC</sub> |
| External clock high time  | t <sub>clkh</sub> | 1.5 | _                    | t <sub>CYC</sub> |
| External clock low time   | t <sub>clkl</sub> | 1.5 | _                    | t <sub>CYC</sub> |
| Input capture pulse width | f <sub>ICPW</sub> | 1.5 | _                    | t <sub>CYC</sub> |

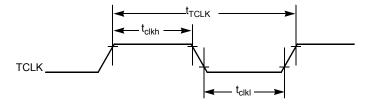


Figure 12. Timer External Clock

19

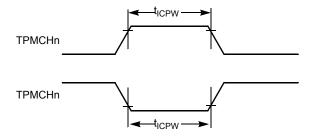


Figure 13. Timer Input Capture Pulse

# 3.9 Analog Comparator (ACMP) Electrical

**Table 12. Analog Comparator Electrical Specifications** 

| Characteristic                              | Symbol             | Min                   | Typical | Max      | Unit |
|---|--------------------|-----------------------|---------|----------|------|
| Supply voltage                              | $V_{DD}$           | 2.7                   | _       | 5.5      | V    |
| Supply current (active)                     | I <sub>DDAC</sub>  | _                     | 20      | 35       | μΑ   |
| Analog input voltage                        | V <sub>AIN</sub>   | V <sub>SS</sub> - 0.3 | _       | $V_{DD}$ | V    |
| Analog input offset voltage <sup>1</sup>    | V <sub>AIO</sub>   | _                     | 20      | 40       | mV   |
| Analog Comparator hysteresis <sup>1</sup>   | $V_{H}$            | 3.0                   | 9.0     | 15.0     | mV   |
| Analog source impedance                     | R <sub>AS</sub>    | _                     | _       | 10       | kΩ   |
| Analog input leakage current                | I <sub>ALKG</sub>  | _                     | _       | 1.0      | μΑ   |
| Analog Comparator initialization delay      | t <sub>AINIT</sub> | _                     | _       | 1.0      | μS   |
| Analog Comparator bandgap reference voltage | $V_{BG}$           | 1.208                 | 1.208   | 1.208    | V    |

<sup>1</sup> These data are characterized but not production tested. Measurements are made with the device entered STOP mode.

### 3.10 Internal Clock Source Characteristics

**Table 13. Internal Clock Source Specifications** 

| Characteristic   | Symbol                  | Min   | Typical <sup>1</sup> | Max     | Unit  |
|--|-------------------------|-------|----------------------|---------|-------|
| Average internal reference frequency — untrimmed   | f <sub>int_ut</sub>     | 25    | 31.25                | 41.66   | kHz   |
| Average internal reference frequency — trimmed   | f <sub>int_t</sub>      | 31.25 | 39.0625 <sup>2</sup> | 39.0625 | kHz   |
| DCO output frequency range — untrimmed   | f <sub>dco_ut</sub>     | 12.8  | 16                   | 21.33   | MHz   |
| DCO output frequency range — trimmed   | f <sub>dco_t</sub>      | 16    | 20 <sup>3</sup>      | 20      | MHz   |
| Resolution of trimmed DCO output frequency at fixed voltage and temperature              | Δf <sub>dco_res_t</sub> | _     | _                    | 0.2     | %fdco |
| Total deviation of trimmed DCO output frequency over voltage and temperature             | $\Delta f_{dco\_t}$     | _     | _                    | 2       | %fdco |
| FLL acquisition time <sup>4,5</sup>  | t <sub>acquire</sub>    | _     | _                    | 1       | ms    |
| Stop recovery time (FLL wakeup to previous acquired frequency) IREFSTEN = 0 IREFSTEN = 1 | t <sub>wakeup</sub>     | _     | 100<br>86            | _       | μS    |

<sup>&</sup>lt;sup>1</sup> Data in typical column was characterized at 3.0 V and 5.0 V, 25 °C or is typical recommended value.

<sup>&</sup>lt;sup>2</sup> This value has been trimmed to 39.0625 kHz when out of factory

<sup>&</sup>lt;sup>3</sup> This value has been trimmed to 20 MHz when out of factory

- $^{\rm 4}~$  This parameter is characterized and not tested on each device.
- <sup>5</sup> This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBILP) to FLL enabled (FEI, FBI).

### 3.11 ADC Characteristics

Table 14. 5 Volt 10-bit ADC Operating Conditions

| Characteristic                           | Conditions   | Symbol            | Min               | Typical <sup>1</sup> | Max               | Unit   |
|--|--|-------------------|-------------------|----------------------|-------------------|--------|
| Supply voltage                           | Absolute   | $V_{DDAD}$        | 2.7               | _                    | 5.5               | V      |
| Supply Voltage                           | Delta to V <sub>DD</sub> (V <sub>DD</sub> – V <sub>DDAD</sub> ) <sup>2</sup> | $\Delta V_{DDAD}$ | -100              | 0                    | 100               | mV     |
| Ground voltage                           | Delta to V <sub>SS</sub> (V <sub>SS</sub> – V <sub>SSAD</sub> ) <sup>2</sup> | $\Delta V_{SSAD}$ | -100              | 0                    | 100               | mV     |
| Ref voltage high                         | _  | V <sub>REFH</sub> | 2.7               | $V_{DDAD}$           | V <sub>DDAD</sub> | V      |
| Ref voltage low                          | _  | V <sub>REFL</sub> | V <sub>SSAD</sub> | V <sub>SSAD</sub>    | V <sub>SSAD</sub> | V      |
| Input voltage                            | _  | V <sub>ADIN</sub> | V <sub>REFL</sub> | _                    | V <sub>REFH</sub> | V      |
| Input capacitance                        | _  | C <sub>ADIN</sub> | _                 | 4.5                  | 5.5               | pF     |
| Input resistance                         | _  | R <sub>ADIN</sub> | _                 | 3                    | 5                 | kΩ     |
| Analog source resistance external to MCU | 10-bit mode<br>f <sub>ADCK</sub> > 4MHz<br>f <sub>ADCK</sub> < 4MHz          | R <sub>AS</sub>   | _                 |                      | 5<br>10           | kΩ     |
|  | 8-bit mode (all valid f <sub>ADCK</sub> )                                    |                   | _                 | _                    | 10                |        |
| ADC conversion clock                     | High speed (ADLPC = 0)   | f                 | 0.4               |                      | 8.0               | MHz    |
| frequency                                | Low power (ADLPC = 1)  | f <sub>ADCK</sub> | 0.4               | _                    | 4.0               | IVITIZ |

<sup>&</sup>lt;sup>1</sup> Typical values assume V<sub>DDAD</sub> = 5.0 V, Temp = 25 °C, f<sub>ADCK</sub> = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

<sup>&</sup>lt;sup>2</sup> DC potential difference.

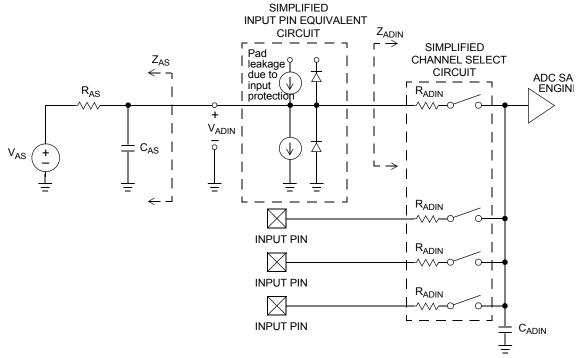


Figure 14. ADC Input Impedance Equivalency Diagram

Table 15. 10-bit ADC Characteristics ( $V_{REFH} = V_{DDAD}$ ,  $V_{REFL} = V_{SSAD}$ )

| Characteristic                                  | Conditions                | С | Symbol             | Min  | Typical <sup>1</sup> | Max | Unit    |
|---|---------------------------|---|--------------------|------|----------------------|-----|---------|
| Supply current ADLPC=1 ADLSMP=1 ADCO=1          |                           | Т | I <sub>DDAD</sub>  | _    | 133                  | _   | μА      |
| Supply current<br>ADLPC=1<br>ADLSMP=0<br>ADCO=1 |                           | Т | I <sub>DDAD</sub>  | _    | 218                  | _   | μΑ      |
| Supply current ADLPC=0 ADLSMP=1 ADCO=1          |                           | Т | I <sub>DDAD</sub>  | _    | 327                  | _   | μА      |
| Supply current ADLPC=0 ADLSMP=0 ADCO=1          | V <sub>DDAD</sub> ≤ 5.5 V | Р | I <sub>DDAD</sub>  | _    | 0.582                | 1   | mA      |
| Supply current                                  | Stop, Reset, Module Off   |   | I <sub>DDAD</sub>  |      | 0.011                | 1   | μА      |
| ADC asynchronous clock                          | High Speed (ADLPC = 0)    | Р | f                  | 2    | 3.3                  | 5   | MHz     |
| source  | Low Power (ADLPC = 1)     |   | f <sub>ADACK</sub> | 1.25 | 2                    | 3.3 | IVII IZ |

Table 15. 10-bit ADC Characteristics ( $V_{REFH} = V_{DDAD}$ ,  $V_{REFL} = V_{SSAD}$ ) (continued)

| Characteristic                 | Conditions                | С                          | Symbol             | Min                  | Typical <sup>1</sup> | Max              | Unit             |                  |
|--------------------------------|---------------------------|----------------------------|--------------------|----------------------|----------------------|------------------|------------------|------------------|
| Conversion time (Including     | Short Sample (ADLSMP = 0) | Р                          |                    | _                    | 20                   | _                | ADCK             |                  |
| sample time)                   | Long Sample (ADLSMP = 1)  | P                          | t <sub>ADC</sub>   | _                    | 40                   | _                | cycles           |                  |
| Cample time                    | Short Sample (ADLSMP = 0) | Р                          | 4                  | _                    | 3.5                  | _                | ADCK             |                  |
| Sample time                    | Long Sample (ADLSMP = 1)  | F                          | P LADS             | P t <sub>ADS</sub>   | _                    | 23.5             | _                | cycles           |
| Total upadiusted array         | 10-bit mode               | В                          | P E <sub>TUE</sub> | _                    | ±1                   | ±2.5             | LSB <sup>2</sup> |                  |
| Total unadjusted error         | 8-bit mode                | P ETUE                     |                    | P   E <sub>TUE</sub> | _                    | ±0.5             | ±1.0             | LOB              |
|                                | 10-bit mode               | Р                          | DNL                | _                    | ±0.5                 | ±1.0             | LSB <sup>2</sup> |                  |
| Differential non-linearity     | 8-bit mode                | F                          |                    | _                    | ±0.3                 | ±0.5             | r2R-             |                  |
|                                | Monotor                   | Monotonicity and no-missir |                    | ng-code gu           | aranteed             |                  |                  |                  |
| Integral pen linearity         | 10-bit mode               | С                          |                    | _                    | ±0.5                 | ±1.0             | LSB <sup>2</sup> |                  |
| Integral non-linearity         | 8-bit mode                |                            | INL                | _                    | ±0.3                 | ±0.5             | LOD              |                  |
| Zero-scale error               | 10-bit mode               | Р                          | _                  | _                    | ±0.5                 | ±1.5             | LSB <sup>2</sup> |                  |
| Zero-scale error               | 8-bit mode                | F                          | E <sub>ZS</sub>    | _                    | ±0.5                 | ±0.5             | LOD              |                  |
| Full-scale error               | 10-bit mode               | Ь                          | Г                  | _                    | ±0.5                 | ±1.5             | LSB <sup>2</sup> |                  |
| $V_{ADIN} = V_{DDA}$           | 8-bit mode                | F                          | P E <sub>FS</sub>  | _                    | ±0.5                 | ±0.5             | LOD              |                  |
| Quantization error             | 10-bit mode               | <u> </u>                   | _                  | _                    | ±0.5                 | LSB <sup>2</sup> |                  |                  |
| Quantization endi              | 8-bit mode                | D                          | E <sub>Q</sub>     | _                    | _                    | ±0.5             | LOD              |                  |
| Input leakage error            | 10-bit mode               | 5 -                        |                    | Е                    | _                    | ±0.2             | ±2.5             | LSB <sup>2</sup> |
| pad leakage <sup>3</sup> * Ras | 8-bit mode                | D                          | E <sub>IL</sub>    | _                    | ±0.1                 | ±1               | LOD              |                  |

Typical values assume V<sub>DDAD</sub> = 5.0 V, Temp = 25 °C, f<sub>ADCK</sub> = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

### 3.12 AC Characteristics

This section describes AC timing characteristics for each peripheral system.

## 3.12.1 Control Timing

**Table 16. Control Timing** 

| Characteristic   | Symbol           | Min | Typical | Max  | Unit |
|--|------------------|-----|---------|------|------|
| Bus frequency (t <sub>cyc</sub> = 1/f <sub>Bus</sub> ) | f <sub>Bus</sub> | DC  |         | 10   | MHz  |
| Real time interrupt internal oscillator period         | t <sub>RTI</sub> | 700 | 1000    | 1300 | μS   |

### MC9RS08LA8 Series MCU Data Sheet, Rev. 2

<sup>&</sup>lt;sup>2</sup> 1 LSB =  $(V_{REFH} - V_{REFL})/2^N$ 

<sup>&</sup>lt;sup>3</sup> Based on input pad leakage current. Refer to pad electrical.

| Table 16. Control Timing (continued) | Table 1 | ۱6. | Control | Timing | (continued) |
|--------------------------------------|---------|-----|---------|--------|-------------|
|--------------------------------------|---------|-----|---------|--------|-------------|

| Characteristic   | Symbol                                | Min      | Typical  | Max | Unit |
|--|---------------------------------------|----------|----------|-----|------|
| External RESET pulse width <sup>1</sup>  | t <sub>extrst</sub>                   | 150      |          | _   | ns   |
| KBI pulse width <sup>2</sup>   | t <sub>KBIPW</sub>                    | 1.5 tcyc |          | _   | ns   |
| KBI pulse width in stop <sup>1</sup>   | t <sub>KBIPWS</sub>                   | 100      |          | _   | ns   |
| Port rise and fall time (load = 50 pF) <sup>3</sup> Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1) | t <sub>Rise</sub> , t <sub>Fall</sub> |          | 11<br>35 |     | ns   |

This is the shortest pulse that is guaranteed to pass through the pin input filter circuitry. Shorter pulses may or may not be recognized.

 $<sup>^3</sup>$  Timing is shown with respect to 20% V<sub>DD</sub> and 80% V<sub>DD</sub> levels. Temperature range –40 °C to 85 °C.

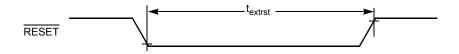


Figure 15. Reset Timing

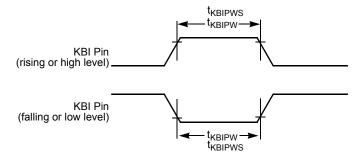


Figure 16. KBI Pulse Width

## 3.13 Flash Specifications

This section provides details about program/erase times and program-erase endurance for the flash memory. For detailed information about program/erase operations, see the reference manual.

**Table 17. Flash Characteristics** 

| Characteristic  | Symbol                | Min  | Typical <sup>1</sup> | Max        | Unit                     |
|---|-----------------------|------|----------------------|------------|--------------------------|
| Supply voltage for program/erase                                | $V_{DD}$              | 2.7  | _                    | 5.5        | V                        |
| Program/Erase voltage   | $V_{PP}$              | 11.8 | 12                   | 12.2       | V                        |
| V <sub>PP</sub> current Program Mass erase                      | I <sub>VPP_prog</sub> |      | _<br>_               | 200<br>100 | μ <b>Α</b><br>μ <b>Α</b> |
| Supply voltage for read operation 0 < f <sub>Bus</sub> < 10 MHz | V <sub>Read</sub>     | 2.7  | _                    | 5.5        | V                        |

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

<sup>&</sup>lt;sup>2</sup> This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

**Table 17. Flash Characteristics (continued)** 

| Characteristic  | Symbol                | Min  | Typical <sup>1</sup> | Max | Unit   |
|---|-----------------------|------|----------------------|-----|--------|
| Byte program time   | t <sub>prog</sub>     | 20   | _                    | 40  | μS     |
| Mass erase time   | t <sub>me</sub>       | 500  | _                    | _   | ms     |
| Cumulative program HV time <sup>2</sup>   | t <sub>hv</sub>       | _    | _                    | 8   | ms     |
| Total cumulative HV time (total of t <sub>me</sub> & t <sub>hv</sub> applied to device) | t <sub>hv_total</sub> | _    | _                    | 2   | hours  |
| HVEN to program setup time  | t <sub>pgs</sub>      | 10   | _                    | _   | μS     |
| PGM/MASS to HVEN setup time   | t <sub>nvs</sub>      | 5    | _                    | _   | μS     |
| HVEN hold time for PGM  | t <sub>nvh</sub>      | 5    | _                    | _   | μS     |
| HVEN hold time for MASS   | t <sub>nvh1</sub>     | 100  | _                    | _   | μS     |
| V <sub>PP</sub> to PGM/MASS setup time  | t <sub>vps</sub>      | 20   | _                    | _   | ns     |
| HVEN to VPP hold time   | t <sub>vph</sub>      | 20   | _                    | _   | ns     |
| V <sub>PP</sub> rise time <sup>3</sup>  | t <sub>vrs</sub>      | 200  | _                    | _   | ns     |
| Recovery time   | t <sub>rcv</sub>      | 1    | _                    | _   | μS     |
| Program/erase endurance<br>T <sub>L</sub> to T <sub>H</sub> = -40 °C to 85 °C           | _                     | 1000 | _                    | _   | cycles |
| Data retention  | t <sub>D_ret</sub>    | 15   | _                    | _   | years  |

Typicals are measured at 25 °C.

<sup>&</sup>lt;sup>3</sup> Fast V<sub>PP</sub> rise time may potentially trigger the ESD protection structure, which may result in over current flowing into the pad and cause permanent damage to the pad. External filtering for the V<sub>PP</sub> power source is recommended. An example V<sub>PP</sub> filter is shown in Figure 17.

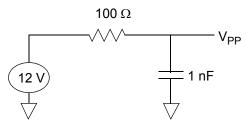
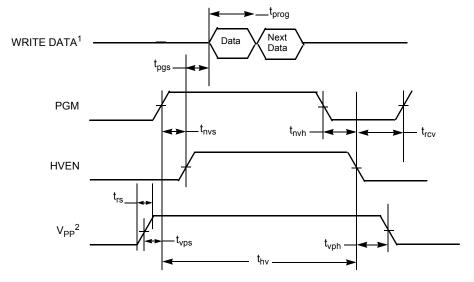


Figure 17. Example V<sub>PP</sub> Filtering

<sup>&</sup>lt;sup>2</sup> th<sub>v</sub> is the cumulative high voltage programming time to the same row before next erase. Same address can not be programmed more than twice before next erase.



- Next Data applies if programming multiple bytes in a single row, refer to MC9RS08LA8 Series Reference Manual
- <sup>2</sup> V<sub>DD</sub> must be at a valid operating voltage before voltage is applied or removed from the V<sub>PP</sub> pin.

MASS

HVEN  $t_{nvs}$   $t_{nvh1}$   $t_{rs}$   $t_{vph}$ 

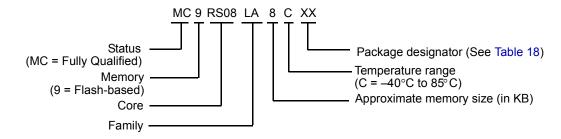
Figure 18. Flash Program Timing

 $^{1}~\rm V_{DD}$  must be at a valid operating voltage before voltage is applied or removed from the  $\rm V_{PP}$  pin.

Figure 19. Flash Mass Erase Timing

# 4 Ordering Information

This section contains ordering information for MC9RS08LA8 devices. See below for an example of the device numbering system.



# 5 Package Information and Mechanical Drawings

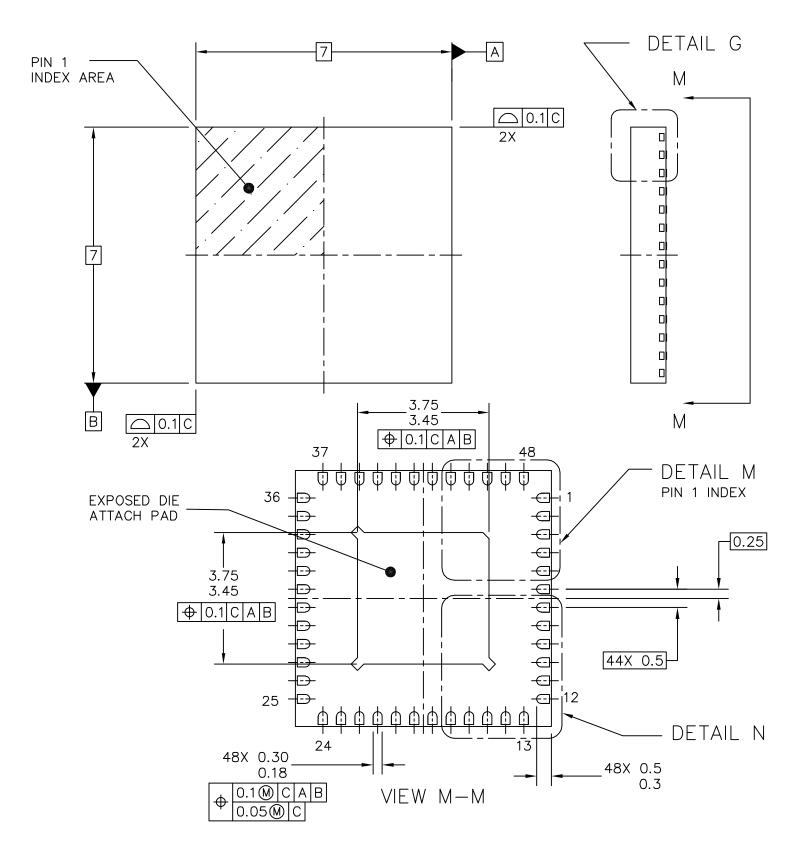
Table 18 provides the available package types and their document numbers. The latest package outline/mechanical drawings are available on the MC9RS08LA8 Series Product Summary pages at http://www.freescale.com.

To view the latest drawing, either:

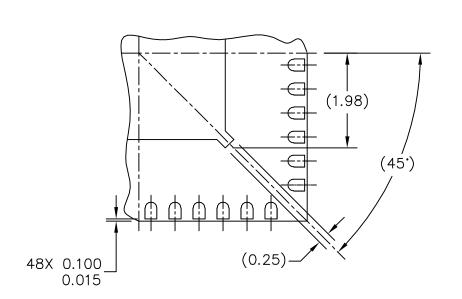
- Click on the appropriate link in Table 18, or
- Open a browser to the Freescale<sup>®</sup> website (http://www.freescale.com), and enter the appropriate document number (from Table 18) in the "Enter Keyword" search box at the top of the page.

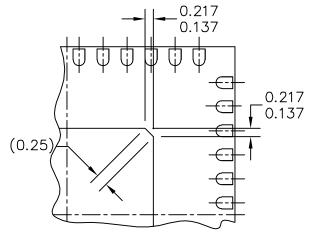
| Device Number        | Men       | nory        | Package    |             |              |
|----------------------|-----------|-------------|------------|-------------|--------------|
| Bevice Humber        | FLASH     | RAM         | Type       | Designator  | Document No. |
| MC9RS08LA8           | 8 KB      | 256 bytes   | 48-Pin QFN | FT          | 98ARL10606D  |
| WIC9R308LA6 8 NB 250 | 200 Dytes | 48-Pin LQFP | LF         | 98ASH00962A |              |

**Table 18. Device Numbering System** 



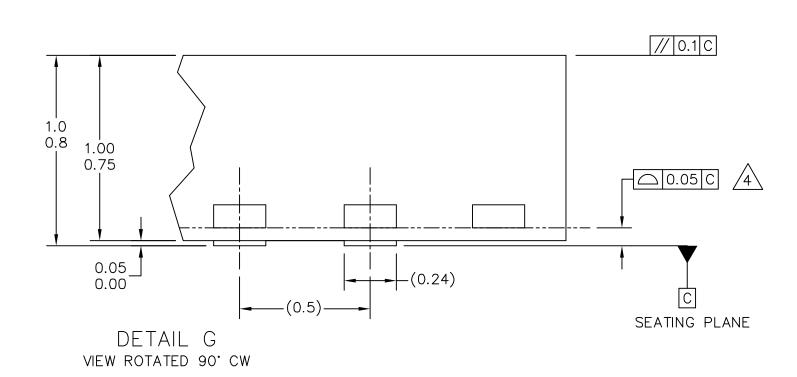
| © FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. | ECHANICA | L OUTLINE    | PRINT VERSION NO  | T TO SCALE  |
|--|----------|--------------|-------------------|-------------|
| TITLE: THERMALLY ENHANCED QUA                        | AD       | DOCUMENT NO  | : 98ARL10606D     | REV: 0      |
| FLAT NON-LEADED PACKAGE                              | ` '      | CASE NUMBER  | : 1975–01         | 29 AUG 2007 |
| 48 TERMINAL, 0.5 PITCH (7 X                          | / X 1) [ | STANDARD: JE | DEC-MO-220 VKKD-2 | 2           |





DETAIL N
PREFERRED CORNER CONFIGURATION

DETAIL M
PREFERED PIN 1 BACKSIDE IDENTIFIER



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|--|------------|--------------|-------------------|-------------|
| TITLE: THERMALLY ENHANCED                            | QUAD       | DOCUMENT NO  | ): 98ARL10606D    | REV: 0      |
| FLAT NON-LEADED PACKA                                | ` ,        | CASE NUMBER  | R: 1975–01        | 29 AUG 2007 |
| 48 TERMINAL, 0.5 PITCH (7                            | ′ X / X 1) | STANDARD: JE | DEC-MO-220 VKKD-2 | 2           |

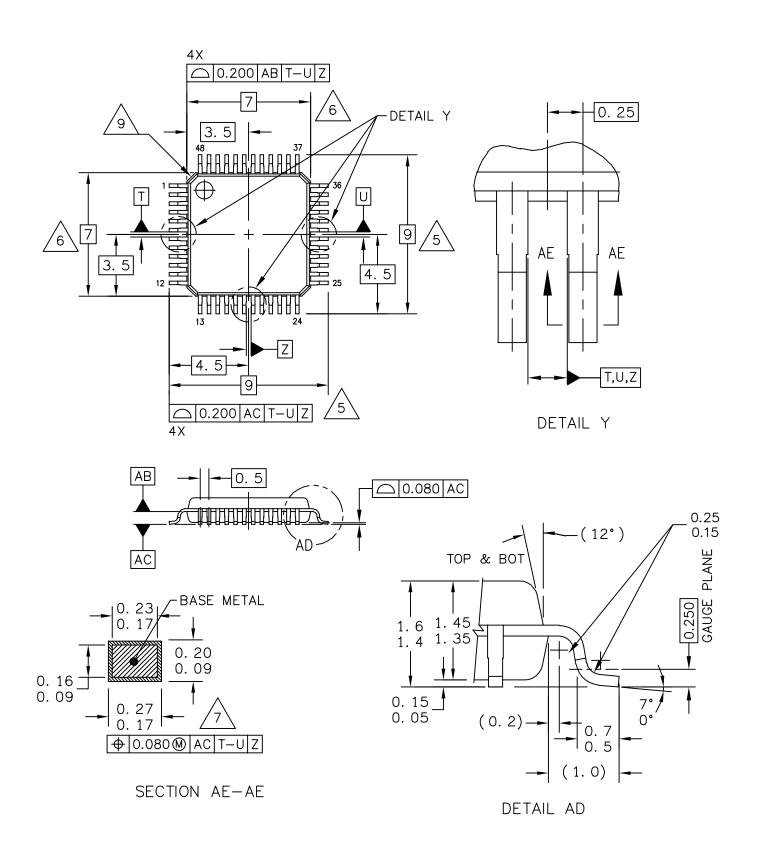
### NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- 3. THE COMPLETE JEDEC DESIGNATOR FOR THIS PACKAGE IS: HF-PQFN.

4. Coplanarity applies to leads, corner leads, and die attach pad.

5. MIN METAL GAP SHOULD BE 0.2MM.

| © FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. | MECHANICA  | L OUTLINE    | PRINT VERSION NO  | T TO SCALE  |
|--|------------|--------------|-------------------|-------------|
| TITLE: THERMALLY ENHANCED                            | QUAD       | DOCUMENT NO  | ): 98ARL10606D    | REV: 0      |
| FLAT NON-LEADED PACKA                                | ` '        | CASE NUMBER  |                   | 29 AUG 2007 |
| 48 TERMINAL, 0.5 PITCH (7                            | / X / X 1) | STANDARD: JE | DEC-MO-220 VKKD-2 | 2           |



| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. | MECHANICAL OUTLINE |                                | PRINT VERSION NO | OT TO SCALE |
|---|--------------------|--------------------------------|------------------|-------------|
| TITLE:  |                    |                                | ): 98ASH00962A   | REV: G      |
| LQFP, 48 LEAD, 0.50 PITCH                               |                    | CASE NUMBER: 932-03 14 APR 200 |                  | 14 APR 2005 |
| (7.0 X 7.0 X  | 1.4)               | STANDARD: JE                   | EDEC MS-026-BBC  |             |

#### NOTES:

- 1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M-1994.
- 2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DATUM PLANE AB IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
- 4. DATUMS T, U, AND Z TO BE DETERMINED AT DATUM PLANE AB.



DIMENSIONS TO BE DETERMINED AT SEATING PLANE AC.



DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.250 PER SIDE. DIMENSIONS DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE AB.



THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.350.

8. MINIMUM SOLDER PLATE THICKNESS SHALL BE 0.0076.



EXACT SHAPE OF EACH CORNER IS OPTIONAL.

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|---|-------------|--------------|------------------|-------------|
| TITLE:  |             |              | ): 98ASH00962A   | REV: G      |
| LQFP, 48 LEAD, 0.   | CASE NUMBER | 2: 932–03    | 14 APR 2005      |             |
| (7.0 X 7.0 X  | 1.4)        | STANDARD: JE | DEC MS-026-BBC   |             |

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